



**ELECTRONIC COPY**

LG715502014  
Report verification at igi.org



June 18, 2025

IGI Report Number **LG715502014**

Description **LABORATORY GROWN DIAMOND**

Shape and Cutting Style **OVAL BRILLIANT**

Measurements **10.09 X 7.19 X 4.55 MM**

**GRADING RESULTS**

Carat Weight **2.07 CARATS**

Color Grade **E**

Clarity Grade **VVS 1**

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**ADDITIONAL GRADING INFORMATION**

Polish **EXCELLENT**

Symmetry **EXCELLENT**

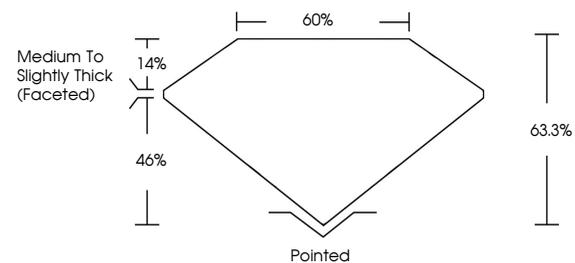
Fluorescence **NONE**

Inscription(s) **IGI LG715502014**

Comments: As Grown - No indication of post-growth treatment.

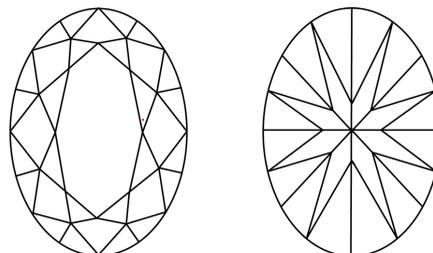
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II

**PROPORTIONS**



Sample Image Used

**CLARITY CHARACTERISTICS**



**KEY TO SYMBOLS**

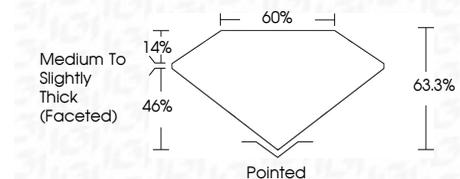
Red symbols indicate internal characteristics.  
Green symbols indicate external characteristics.

**COLOR**

D E F G H I J Faint Very Light Light

**CLARITY**

IF	VS <sup>1-2</sup>	VS <sup>1-2</sup>	SI <sup>1-2</sup>	I <sup>1-3</sup>
Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included



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**IGI**



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OVAL BRILLIANT  
10.09 X 7.19 X 4.55 MM  
2.07 CARATS  
E  
VVS 1  
63.3%  
46%  
14%  
Medium to Slightly Thick (Faceted)  
Pointed  
EXCELLENT  
EXCELLENT  
NONE  
IGI LG715502014

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